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APPLICATION NO. CONFIRMATION NO. FIRST NAMED INVENTOR ATTORNEY DOCKET NO. FILING DATE

09 681,643

05-15/2001

Takatoshi Tsujimura

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PAPER NUMBER

877

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06/11/2003

IBM CORPORATION, T.J. WATSON RESEARCH CENTER P.O BOX 218 YORKTOWN HEIGHTS, NY 10598

EXAMINER

COLEMAN, WILLIAM D

2823

ART UNIT

DATE MAILED: 06/11/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

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Office Action Summary		Application No.	Applicant(s)		
		09/681,643	TSUJIMURA ET AL.		
		Examiner	Art Unit		
		W. David Coleman	2823		
Period f	The MAILING DATE of this communicat or Reply	ion appears on the cover sheet with	h the correspondence address		
THE - Extending - If the - If NO - Faile - Any	MAILING DATE OF THIS COMMUNICATE on sions of time may be available under the provisions of 37 or SIX (6) MONTHS from the mailing date of this communicate period for reply specified above is less than thirty (30) date of period for reply is specified above, the maximum statutor are to reply within the set or extended period for reply will, the reply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	TION. CFR 1.136(a). In no event, however, may a relation. ys, a reply within the statutory minimum of thirty by period will apply and will expire SIX (6) MONT by statute, cause the application to become ABA	(30) days will be considered timely. HS from the mailing date of this communication. NDONED (35 U.S.C. § 133).		
1)[_	Responsive to communication(s) filed	on <u>30 April 2003</u> .			
2a) <u></u> ☐	This action is FINAL . 2b)	∑ This action is non-final.			
3)	Since this application is in condition for closed in accordance with the practice	-			
Disposit	tion of Claims				
4)[-	Claim(s) 1-16 is/are pending in the app	lication.			
4a) Of the above claim(s) 11-16 is/are withdrawn from consideration.					
5)□	5) Claim(s) is/are allowed.				
6)[-]	6)⊡ Claim(s) <u>1-10</u> is/are rejected.				
7)	Claim(s) is/are objected to.				
	Claim(s) are subject to restriction	and/or election requirement.			
· · · —	tion Papers				
, —	The specification is objected to by the Ex		- C		
10)	The drawing(s) filed on is/are: a)				
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). 11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.					
11)	If approved, corrected drawings are require		Sapproved by the Examiner.		
12)	The oath or declaration is objected to by	• •			
,	under 35 U.S.C. §§ 119 and 120	the Examiner.			
_	Acknowledgment is made of a claim for	foreign priority under 35 LLS C &	119(a)-(d) or (f)		
•	Acknowledgment is made or a claim for □ All b) □ Some * c) □ None of:	Toreign priority under 55 0.0.0. §	113(a)-(a) or (i).		
a,		suments have been received			
	1. Certified copies of the priority doc2. Certified copies of the priority doc		onlication No		
*	·	onal Bureau (PCT Rule 17.2(a)).			
14)	Acknowledgment is made of a claim for d	lomestic priority under 35 U.S.C. §	§ 119(e) (to a provisional application).		
·	a) The translation of the foreign langua				
	Acknowledgment is made of a claim for o				

3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____. U.S. Patent and Trademark Office

PTO-326 (Rev. 04-01)

1) Notice of References Cited (PTO-892)

2) Notice of Draftsperson's Patent Drawing Review (PTO-948)

Attachment(s)

6) Other:

4) Interview Summary (PTO-413) Paper No(s). ______.

5) Notice of Informal Patent Application (PTO-152)

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DETAILED ACTION

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on April 30, 2003 has been entered.

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ohnuma et al., U.S. Patent 6,072,193 in view of Gardner et al., U.S. Patent 6,066,519.
- 3. Pertaining to claims 1 and 2, <u>Ohnuma</u> discloses a semiconductor process substantially as claimed. See **FIGS. 1A-2D**, where <u>Ohnuma</u> teaches a manufacturing method of an active matrix device (column 17, line 62) including a top gate type TFT, which comprises a process of forming the top gate type TFT, wherein the process of forming the top gate type TFT includes the steps of:

 arranging a substrate **101** having source **125** and drain electrodes **126** formed therein in the processing chamber; doping the source and drain electrodes with P (phosphorous), (column

3, lines 51-54); and forming an a-Si layer 103 and a gate insulating film 104 in the processing

chamber. However, Ohnuma fails to disclose forming an oxide film on an inner wall of a CVD

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processing chamber. Gardner teaches forming an oxide on an inner wall of a CVD processing chamber (column 6, lines 8-14). In view of Gardner, it would have been obvious to one of ordinary skill in the art because when forming a gate dielectric residual oxide forms on the chamber walls (column 6, lines 10-12).

- 4. Pertaining to claim 2, Ohnuma fails to disclose removing the oxide film form the inner wall after the step of forming the a-Si layer and the gate insulating layer. Gardner teaches the step of removing oxide between runs. In view Gardner, it would have been obvious to one of ordinary skill in the are to remove oxide from the chamber walls after the step of forming the a-Si layer and the gate insulating film because the a silicon gate dielectric layer may be formed in a highly controlled manner (column 6, lines 21-23).
- 5. Pertaining to claim 3, Ohnuma teaches a manufacturing method of an active matrix device according to claim 1,

wherein the oxide film contains SiOx.

- 6. Pertaining to claim 4, Ohnuma teaches a manufacturing method of an active matrix device according to claim 1, wherein the active matrix device is a liquid crystal display (column 17, line 62).
- Pertaining to claim 5, Ohnuma teaches a manufacturing method of an active matrix device according to claim 1, wherein the active matrix device is an electroluminescence display (column 17, line 62).
- 8. Pertaining to claim 6, Ohnuma teaches a manufacturing method of an active matrix device according to claim 2, wherein the oxide film contains SiOx.

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- 9. Pertaining to claim 7, Ohnuma teaches a manufacturing method of an active matrix device according to claim 2, wherein the active matrix device is a liquid crystal display.
- 10. Pertaining to claim 8, Ohnuma teaches a manufacturing method of an active matrix device according to claim 3, wherein the active matrix device is a liquid crystal display.
- Pertaining to claim 9, Ohnuma teaches a manufacturing method of an active matrix device according to claim 2, wherein the active matrix device is an electroluminescence display.
- 12. Pertaining to claim 10, Ohnuma teaches a manufacturing method of an active matrix device according to claim 3, wherein the active matrix device is an electroluminescence display.

Conclusion

13. Any inquiry concerning this communication or earlier communications from the examiner should be directed to W. David Coleman whose telephone number is 703-305-0004. The examiner can normally be reached on 9:00 AM-5:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on 703-306-2794. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7721 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

W. David Coleman Primary Examiner Art Unit 2823

Millib. J.